

Surface Mount Glass Passivated Rectifiers 贴片式玻璃钝化整流器

Reverse Voltage - 50 to 1000Volts
反向电压 50-1000V
Forward Current - 2.0 Amperes
正向电流 2.0A

Features 特征

- For surface mounted applications 适用于表面贴装
 - Low reverse leakage current 反向漏电流小
 - Low forward voltage drop 正向压降低
 - High surge capacity 耐浪涌能力高
 - Meet UL flammability classification 94V-0
- 符合UL 94V-0阻燃等级

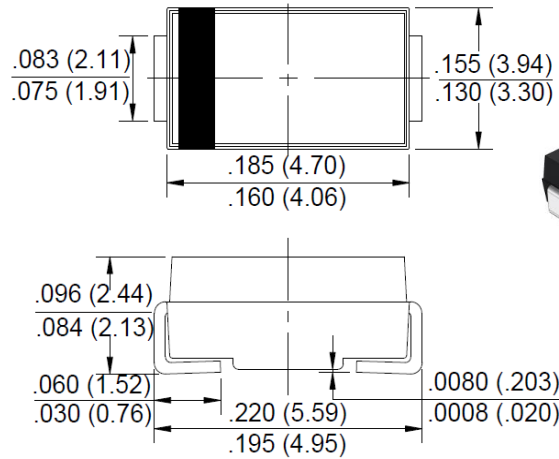
Mechanical Data 外观信息

- Case: JEDEC SMB molded plastic 封装: SMB塑封
- Polarity: Color band denotes cathode 极性: 阴极色环标识
- Mounting position: Any 安装位置: 不限

Applications 应用

- For use in low voltage, high frequency inverters, polarity protection applications
- 应用于低压, 高频变换器, 极性保护

SMB



Package Outline Dimensions in Inches (Millimeters)
 封装外观尺寸单位英寸(毫米)

Maximum Ratings and Electrical Characteristics 最大额定值及电气特性

Rating at 25°C ambient temperature unless otherwise specified. 环境温度25°C, 除非特别说明。
 Single phase, half wave, 60Hz, resistive or inductive load. 单相半波, 60Hz, 阻性或感性负载。
 For capacitive load, derate current by 20%. 对于电容性负载, 降低20%的额定电流。

Characteristics 特性	Symbol 符号	S2A	S2B	S2D	S2G	S2J	S2K	S2M	Unit 单位
Maximum Repetitive Peak Reverse Voltage 最大重复峰值反向电压	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage 最大有效反向电压	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage 最大直流阻断电压	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T _L =100 °C 最大正向平均整流电流	I _(AV)	2.0							A
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method) 8.3mS单一正弦半波叠加在额定负载上的浪涌能力 (JEDEC方法)	I _{FSM}	60							A
I ² t Rating for Fusing (t<8.3mS) 熔断额定值 (t<8.3mS)	I ² t	14.9							A ² s
Peak Forward Voltage at 2.0A DC (Note1) 在2.0 A 电流下的正向峰值电压 (备注1)	V _F	1.0							V
Maximum DC Reverse Current @T _J =25°C at Rated DC Blocking Voltage @T _J =125°C 在额定直流电压下的最大反向直流电流	I _R	5.0							uA
Typical Junction Capacitance (Note 2) 典型结电容	C _J	20							pF
Typical Thermal Resistance Junction to Lead 结到引脚的典型热阻值	R _{θJL}	20							°C/W
Operating Junction Temperature Range 结温工作范围	T _J	-55 to+150							°C
Storage Temperature Range 储存温度范围	T _{STG}	-55 to+150							°C

Notes: 1. 300uS pulse width, 2% duty cycle. 300uS脉宽, 2%占空比。

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC. 在1MHz, 4.0V条件下测试

3. The typical data above is for reference only. 典型值仅供参考。

Fig. 1 - Forward Current Derating Curve

图1 正向电流降额曲线

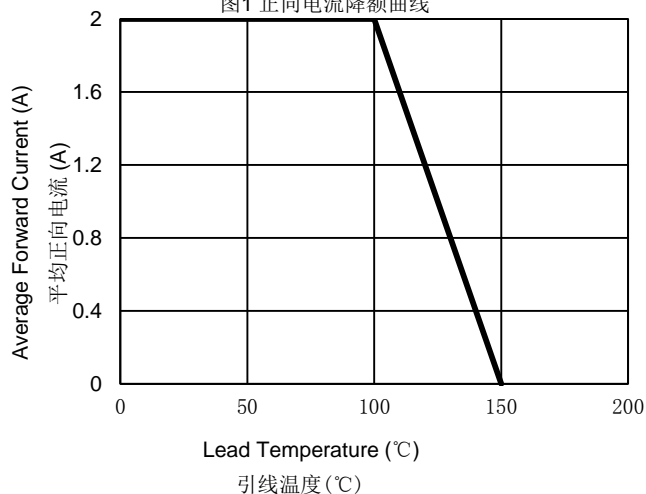


Fig. 2 - Maximum Non-Repetitive Surge Current

图2 最大不重复正向浪涌曲线

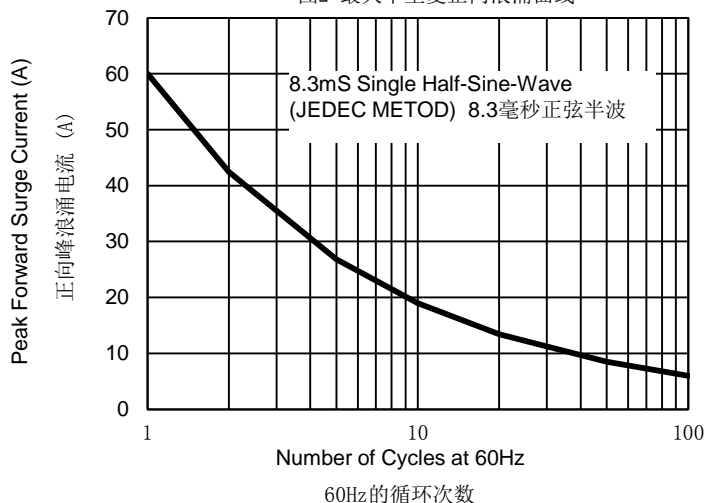


Fig. 3 - Typical Reverse Characteristics

图3 典型的反向特性

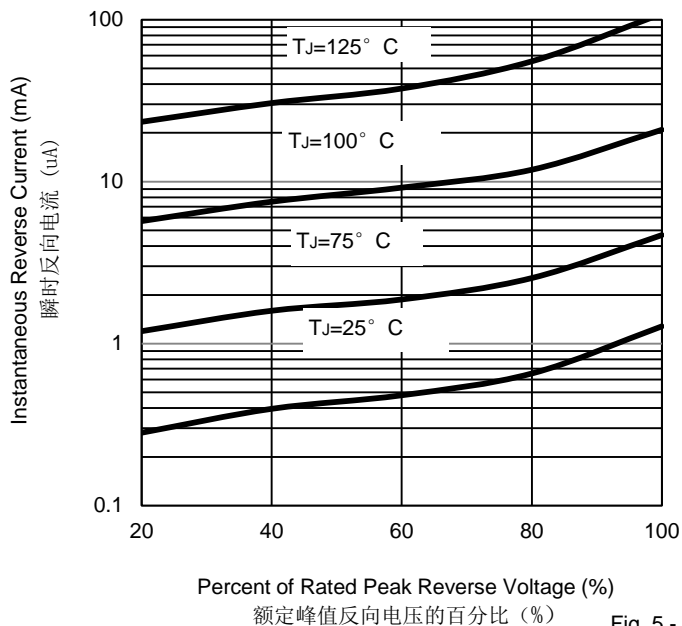
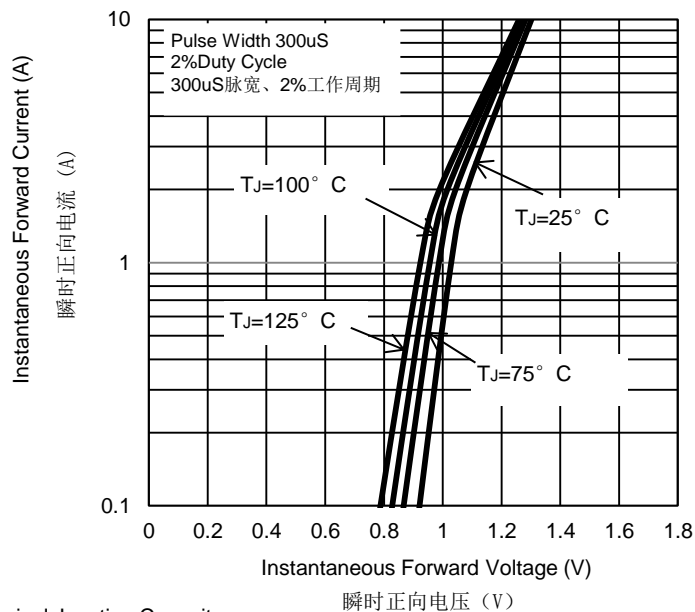


Fig. 4 - Typical Forward Characteristics

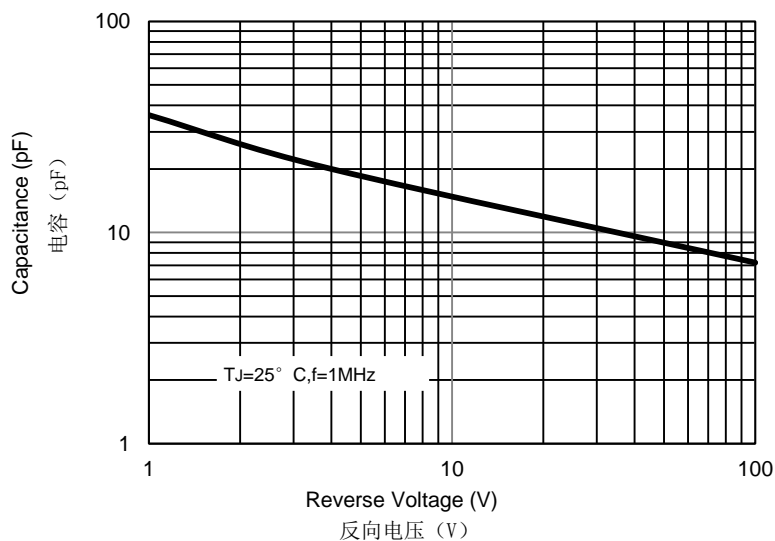
图4 典型的正向特性



Percent of Rated Peak Reverse Voltage (%)
额定峰值反向电压的百分比 (%)

Fig. 5 - Typical Junction Capacitance

图5 典型的结电容



The curve above is for reference only. 曲线图仅供参考。